

DOCKET NO. : LIN 12-37

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Wen Lin, et al.

For: SEMICONDUCTOR DEVICE HAVING A DOPED LATTICE
MATCHING LAYER AND A METHOD OF MANUFACTURE
THEREFOR

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

I hereby certify that this correspondence, including the attachments listed, is being deposited with the United States Postal Service, Express Mail - Post Office to Addressee, Receipt No. <u>EV 312641072 US</u> , in an envelope addressed to Commissioner of Patents, Alexandria, VA 22313-1450, on the date shown below.	
<u>3-31-2004</u> Date of Mailing	<u>Elizabeth Schumacher</u> Signature of person mailing

Sir:

PRELIMINARY AMENDMENT

Before examination of the above-identified application, please amend it as follows:

IN THE SPECIFICATION

Please amend the specification by inserting before the first line the sentence:

--This Application is a Divisional of prior Application Serial No. 10/003,873 filed on
now, U.S. Patent No. 6,737,339
October 24, 2001, ~~currently pending~~, to Wen Lin, et al.. The above-listed Application is commonly
assigned with the present invention and is incorporated herein by reference as if reproduced herein
in its entirety under Rule 1.53(b).--

WLF
a/2/04